## **DISCRETE SEMICONDUCTORS**

# DATA SHEET

# **PDTC143E series** NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$

Product specification Supersedes data of 2004 Mar 18 2004 Aug 05





## PDTC143E series

#### **FEATURES**

- Built-in bias resistors
- · Simplified circuit design
- Reduction of component count
- Reduced pick and place costs.

#### **APPLICATIONS**

- · General purpose switching and amplification
- · Inverter and interface circuits
- Circuit driver.

### **QUICK REFERENCE DATA**

| SYMBOL           | PARAMETER                 | TYP. | MAX. | UNIT |
|------------------|---------------------------|------|------|------|
| V <sub>CEO</sub> | collector-emitter voltage | _    | 50   | V    |
| Io               | output current (DC)       | _    | 100  | mA   |
| R1               | bias resistor             | 4.7  | _    | kΩ   |
| R2               | bias resistor             | 4.7  | _    | kΩ   |

#### **DESCRIPTION**

NPN resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

#### **PRODUCT OVERVIEW**

| TYPE NUMBER  | PACE          | (AGE   | MARKING CODE <sup>(1)</sup> | DND COMPLEMENT |  |
|--------------|---------------|--------|-----------------------------|----------------|--|
| I TPE NUMBER | PHILIPS       | EIAJ   | WARKING CODE                | PNP COMPLEMENT |  |
| PDTC143EE    | SOT416        | SC-75  | 02                          | PDTA143EE      |  |
| PDTC143EEF   | SOT490        | SC-89  | 51                          | PDTA143EEF     |  |
| PDTC143EK    | SOT346        | SC-59  | 02                          | PDTA143EK      |  |
| PDTC143EM    | SOT883        | SC-101 | E1                          | PDTA143EM      |  |
| PDTC143ES    | SOT54 (TO-92) | SC-43  | TC143E                      | PDTA143ES      |  |
| PDTC143ET    | SOT23         | -      | *02                         | PDTA143ET      |  |
| PDTC143EU    | SOT323        | SC-70  | *02                         | PDTA143EU      |  |

### Note

<sup>1. \* =</sup> p: Made in Hong Kong.

<sup>\* =</sup> t: Made in Malaysia.

<sup>\* =</sup> W: Made in China.

# NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$

## PDTC143E series

### SIMPLIFIED OUTLINE, SYMBOL AND PINNING

| TYPE NUMBER  | CIMPLIFIED OUTLINE AND CYMPOL                    |       | PINNING                      |
|--|--|-------|------------------------------|
| TYPE NUMBER  | SIMPLIFIED OUTLINE AND SYMBOL                    | PIN   | DESCRIPTION                  |
| PDTC143ES  | R1   | 1 2 3 | base<br>collector<br>emitter |
| PDTC143EE PDTC143EEF PDTC143EK PDTC143ET PDTC143EU | Top view  Top view  Top view  Top view  Top view | 1 2 3 | base<br>emitter<br>collector |
| PDTC143EM  | 2 R1 R2 2 bottom view MHC506                     | 1 2 3 | base<br>emitter<br>collector |

## NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$

## PDTC143E series

#### **ORDERING INFORMATION**

| TYPE NUMBER  |      | PACKAGE   |         |  |  |  |  |  |  |
|--------------|------|---|---------|--|--|--|--|--|--|
| I TPE NUMBER | NAME | DESCRIPTION   | VERSION |  |  |  |  |  |  |
| PDTC143EE    | _    | plastic surface mounted package; 3 leads  | SOT416  |  |  |  |  |  |  |
| PDTC143EEF   | _    | plastic surface mounted package; 3 leads  | SOT490  |  |  |  |  |  |  |
| PDTC143EK    | _    | plastic surface mounted package; 3 leads  | SOT346  |  |  |  |  |  |  |
| PDTC143EM    | _    | leadless ultra small plastic package; 3 solder lands; body $1.0 \times 0.6 \times 0.5 \text{ mm}$ | SOT883  |  |  |  |  |  |  |
| PDTC143ES    | _    | plastic single-ended leaded (through hole) package; 3 leads                                       | SOT54   |  |  |  |  |  |  |
| PDTC143ET    | _    | plastic surface mounted package; 3 leads  | SOT23   |  |  |  |  |  |  |
| PDTC143EU    | _    | plastic surface mounted package; 3 leads  | SOT323  |  |  |  |  |  |  |

### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL           | PARAMETER                     | CONDITIONS               | MIN. | MAX. | UNIT |
|------------------|-------------------------------|--------------------------|------|------|------|
| V <sub>CBO</sub> | collector-base voltage        | open emitter             | _    | 50   | V    |
| V <sub>CEO</sub> | collector-emitter voltage     | open base                | _    | 50   | V    |
| V <sub>EBO</sub> | emitter-base voltage          | open collector           | _    | 10   | V    |
| VI               | input voltage                 |                          |      |      |      |
|                  | positive                      |                          | _    | +30  | V    |
|                  | negative                      |                          | _    | -10  | V    |
| Io               | output current (DC)           |                          | _    | 100  | mA   |
| I <sub>CM</sub>  | peak collector current        |                          | _    | 100  | mA   |
| P <sub>tot</sub> | total power dissipation       | T <sub>amb</sub> ≤ 25 °C |      |      |      |
|                  | SOT54                         | note 1                   | _    | 500  | mW   |
|                  | SOT23                         | note 1                   | _    | 250  | mW   |
|                  | SOT346                        | note 1                   | _    | 250  | mW   |
|                  | SOT323                        | note 1                   | _    | 200  | mW   |
|                  | SOT416                        | note 1                   | _    | 150  | mW   |
|                  | SOT883                        | notes 2 and 3            | _    | 250  | mW   |
|                  | SOT490                        | notes 1 and 2            | _    | 250  | mW   |
| T <sub>stg</sub> | storage temperature           |                          | -65  | +150 | °C   |
| Tj               | junction temperature          |                          | _    | 150  | °C   |
| T <sub>amb</sub> | operating ambient temperature |                          | -65  | +150 | °C   |

#### **Notes**

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60  $\mu m$  copper strip line.

# NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$

## PDTC143E series

### THERMAL CHARACTERISTICS

| SYMBOL               | PARAMETER                                   | CONDITIONS    | VALUE | UNIT |
|----------------------|---|---------------|-------|------|
| R <sub>th(j-a)</sub> | thermal resistance from junction to ambient | in free air   |       |      |
|                      | SOT54                                       | note 1        | 250   | K/W  |
|                      | SOT23                                       | note 1        | 500   | K/W  |
|                      | SOT346                                      | note 1        | 500   | K/W  |
|                      | SOT323                                      | note 1        | 625   | K/W  |
|                      | SOT416                                      | note 1        | 833   | K/W  |
|                      | SOT883                                      | notes 2 and 3 | 500   | K/W  |
|                      | SOT490                                      | notes 1 and 2 | 500   | K/W  |

### **Notes**

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60  $\mu m$  copper strip line.

### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

| SYMBOL             | PARAMETER                            | CONDITIONS   | MIN. | TYP. | MAX. | UNIT |
|--------------------|--------------------------------------|--|------|------|------|------|
| I <sub>CBO</sub>   | collector-base cut-off current       | V <sub>CB</sub> = 50 V; I <sub>E</sub> = 0 A                               | _    | _    | 100  | nA   |
| I <sub>CEO</sub>   | collector-emitter cut-off current    | V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A                               | _    | _    | 1    | μΑ   |
|                    |                                      | $V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}; T_{j} = 150 ^{\circ}\text{C}$ | _    | _    | 50   | μΑ   |
| I <sub>EBO</sub>   | emitter-base cut-off current         | $V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$                                | _    | _    | 900  | μΑ   |
| h <sub>FE</sub>    | DC current gain                      | V <sub>CE</sub> = 5 V; I <sub>C</sub> = 10 mA                              | 30   | _    | _    |      |
| V <sub>CEsat</sub> | collector-emitter saturation voltage | $I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$                                | _    | _    | 150  | mV   |
| $V_{i(off)}$       | input-off voltage                    | $I_C = 100 \mu\text{A};  V_{CE} = 5 \text{V}$                              | _    | 1.1  | 0.5  | V    |
| V <sub>i(on)</sub> | input-on voltage                     | $I_C = 20 \text{ mA}; V_{CE} = 0.3 \text{ V}$                              | 2.5  | 1.9  | _    | V    |
| R1                 | input resistor                       |  | 3.3  | 4.7  | 6.1  | kΩ   |
| R2                 | resistor ratio                       |  | 0.8  | 1    | 1.2  |      |
| R1                 |                                      |  |      |      |      |      |
| C <sub>c</sub>     | collector capacitance                | $I_E = I_e = 0 \text{ A}; V_{CB} = 10 \text{ V};$<br>f = 1  MHz            | _    | _    | 2.5  | pF   |
|                    |                                      | 1 - 1 1011 12  |      |      | 1    |      |

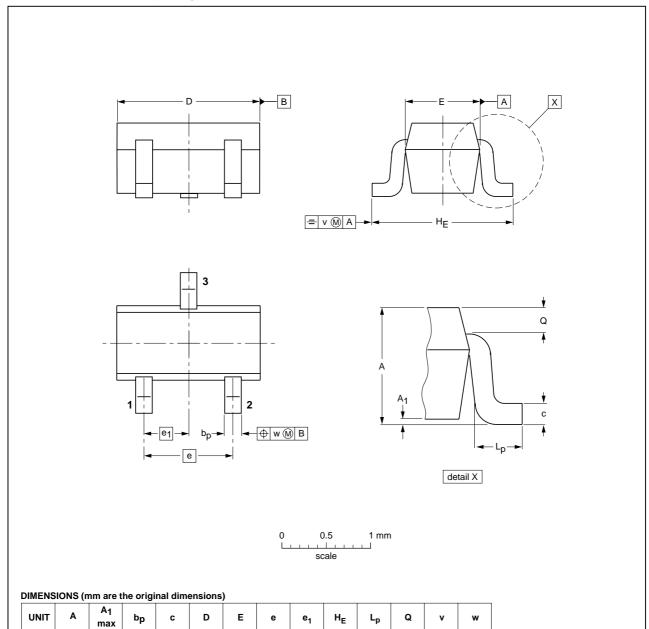
# NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$

## PDTC143E series

### **PACKAGE OUTLINES**

### Plastic surface mounted package; 3 leads

**SOT416** 



| OUTLINE |     | REFER | ENCES | EUROPEAN   | ISSUE DATE |  |
|---------|-----|-------|-------|------------|------------|--|
| VERSION | IEC | JEDEC | EIAJ  | PROJECTION | 1990E DATE |  |
| SOT416  |     |       | SC-75 |            | 97-02-28   |  |

1.75

1

0.5

0.45

0.23

0.2

0.2

2004 Aug 05 6

0.30

0.95

0.25

0.10

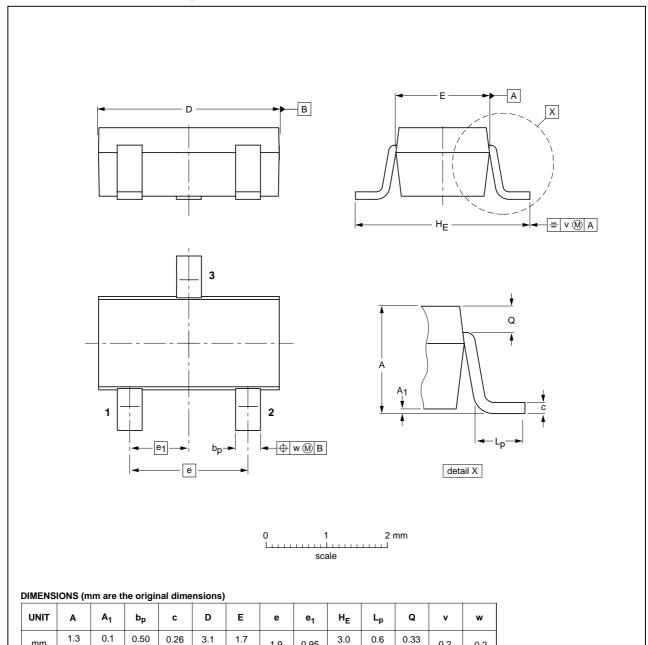
1.8

## NPN resistor-equipped transistors; $R1 = 4.7 \text{ k}\Omega$ , $R2 = 4.7 \text{ k}\Omega$

## PDTC143E series

### Plastic surface mounted package; 3 leads

**SOT346** 



| OUTLINE | REFERENCES |        |       | EUROPEAN   | ISSUE DATE |  |
|---------|------------|--------|-------|------------|------------|--|
| VERSION | IEC        | JEDEC  | EIAJ  | PROJECTION | ISSUE DATE |  |
| SOT346  |            | TO-236 | SC-59 |            | 98-07-17   |  |

0.95

0.2

0.2

1.9

2004 Aug 05 7

1.0

0.013

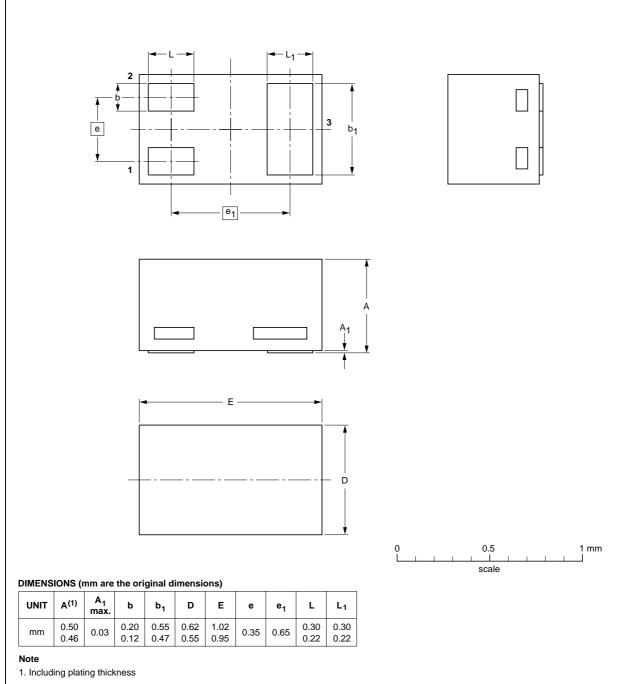
0.35

# NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$

## PDTC143E series

### Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

**SOT883** 



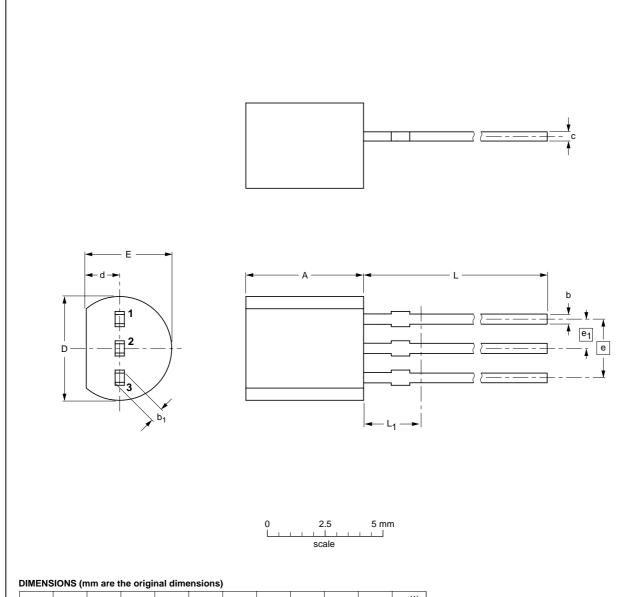
| OUTLINE |     | REFER | ENCES  | EUROPEAN   | ISSUE DATE                      |  |
|---------|-----|-------|--------|------------|---------------------------------|--|
| VERSION | IEC | JEDEC | JEITA  | PROJECTION | ISSUE DATE                      |  |
| SOT883  |     |       | SC-101 |            | <del>03-02-05</del><br>03-04-03 |  |

# NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$

## PDTC143E series

### Plastic single-ended leaded (through hole) package; 3 leads

SOT54



| UNIT | Α          | b            | b <sub>1</sub> | С            | D          | d          | E          | е    | e <sub>1</sub> | L            | L <sub>1</sub> <sup>(1)</sup><br>max. |
|------|------------|--------------|----------------|--------------|------------|------------|------------|------|----------------|--------------|---------------------------------------|
| mm   | 5.2<br>5.0 | 0.48<br>0.40 | 0.66<br>0.55   | 0.45<br>0.38 | 4.8<br>4.4 | 1.7<br>1.4 | 4.2<br>3.6 | 2.54 | 1.27           | 14.5<br>12.7 | 2.5                                   |

#### Note

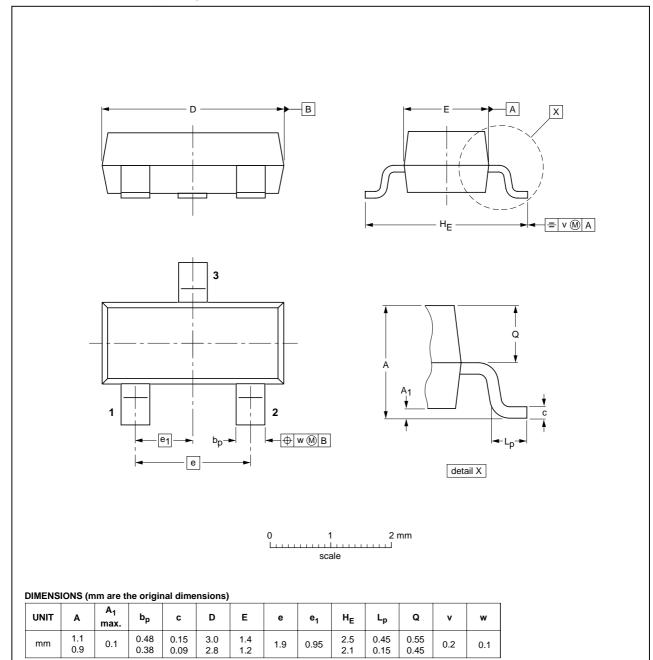
1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

| OUTLINE |     | REFER | FERENCES EUROPEAN ISSUE |  |            |                                 |  |
|---------|-----|-------|-------------------------|--|------------|---------------------------------|--|
| VERSION | IEC | JEDEC | JEITA                   |  | PROJECTION | ISSUE DATE                      |  |
| SOT54   |     | TO-92 | SC-43A                  |  |            | <del>97-02-28</del><br>04-06-28 |  |

## PDTC143E series

### Plastic surface mounted package; 3 leads

SOT23

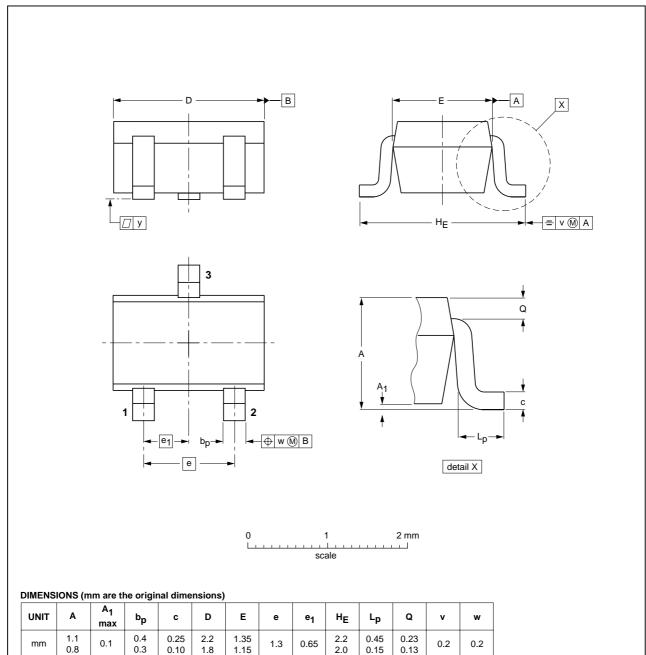


| OUTLINE | REFERENCES |          |      |  | EUROPEAN   | ISSUE DATE                       |
|---------|------------|----------|------|--|------------|----------------------------------|
| VERSION | IEC        | JEDEC    | EIAJ |  | PROJECTION | ISSUE DATE                       |
| SOT23   |            | TO-236AB |      |  |            | <del>-97-02-28</del><br>99-09-13 |

## PDTC143E series

### Plastic surface mounted package; 3 leads

SOT323

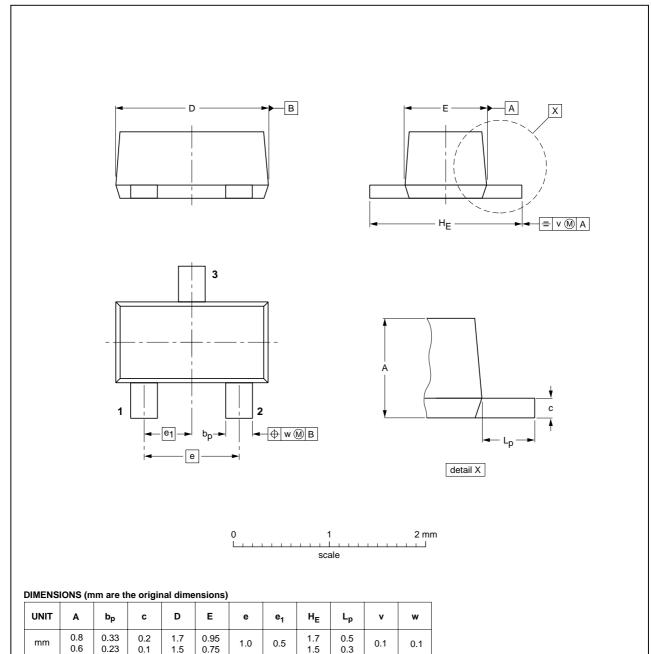


| OUTLINE | REFERENCES |       |       |  | EUROPEAN   | ISSUE DATE |
|---------|------------|-------|-------|--|------------|------------|
| VERSION | IEC        | JEDEC | EIAJ  |  | PROJECTION | ISSUE DATE |
| SOT323  |            |       | SC-70 |  |            | 97-02-28   |

## PDTC143E series

### Plastic surface mounted package; 3 leads

SOT490



| OUTLINE | REFERENCES |       |       |  | EUROPEAN   | ISSUE DATE |
|---------|------------|-------|-------|--|------------|------------|
| VERSION | IEC        | JEDEC | EIAJ  |  | PROJECTION | ISSUE DATE |
| SOT490  |            |       | SC-89 |  |            | 98-10-23   |

## NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 4.7 k $\Omega$

### PDTC143E series

#### **DATA SHEET STATUS**

| LEVEL | DATA SHEET<br>STATUS <sup>(1)</sup> | PRODUCT<br>STATUS(2)(3) | DEFINITION   |
|-------|-------------------------------------|-------------------------|--|
| I     | Objective data                      | Development             | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.  |
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- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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